

# BLP9H10S-350A

Power LDMOS transistor

Rev. 1 — 6 July 2021

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

350 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 600 MHz to 960 MHz.

**Table 1. Typical performance**

Typical RF performance at  $T_{case} = 25\text{ °C}$  in an asymmetrical Doherty circuit;  $V_{DS} = 48\text{ V}$ ;  $I_{Dq} = 400\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.5\text{ V}$ , unless otherwise specified.

Test signal	f	$V_{DS}$	$P_{L(AV)}$	$G_p$	$\eta_D$	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	617 to 652	48	47.5	19	53.4	-34.9 [1]
	859 to 894	48	47.7	18.5	53	-33.3 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

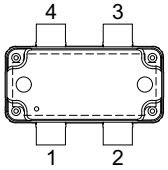
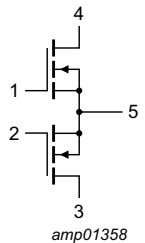
- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internal integrated wideband input for ease of use
- Integrated double sided ESD protection
- For RoHS compliance see the product details on the Ampleon website

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 600 MHz to 960 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	gate1		
2	gate2		
3	drain2		
4	drain1		
5	source <sup>[1]</sup>		

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLP9H10S-350A	-	overmolded plastic earless flanged package; 4 leads	OMP-780-4F-1

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	105	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-6	+11	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-6	+11	V
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature		<sup>[1]</sup> -	200	°C
$T_{case}$	case temperature	operating	<sup>[1]</sup> -40	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$V_{DS} = 48\text{ V}; I_{Dq} = 400\text{ mA (main)};$ $V_{GS(amp)peak} = 0.5\text{ V}; T_{case} = 80\text{ °C}$		
		$P_L = 59\text{ W}$	0.66	K/W
		$P_L = 74\text{ W}$	0.6	K/W

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Main device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1\text{ mA}$	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 100\text{ mA}$	1.5	1.9	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 48\text{ V}; I_D = 400\text{ mA}$	1.45	2.0	2.45	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 50\text{ V}$	-	-	1.4	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	-	16.8	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 5\text{ A}$	-	7.0	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 3.5\text{ A}$	-	220	370	$\text{m}\Omega$
<b>Peak device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1.5\text{ mA}$	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 150\text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 48\text{ V}; I_D = 600\text{ mA}$	1.7	2.2	2.7	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 50\text{ V}$	-	-	1.4	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	-	24.5	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 7.5\text{ A}$	-	10.3	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 5.25\text{ A}$	-	151	250	$\text{m}\Omega$

**Table 7. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH;  $f_1 = 619.5\text{ MHz}; f_2 = 649.5\text{ MHz}$ ; RF performance at  $V_{DS} = 48\text{ V}; I_{Dq} = 400\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.5\text{ V}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 617 MHz to 652 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$P_{L(AV)} = 56.2\text{ W}$	16.7	18.6	-	dB
$RL_{in}$	input return loss	$P_{L(AV)} = 56.2\text{ W}$	-	-15	-9	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 56.2\text{ W}$	46	52	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 56.2\text{ W}$	-	-33	-29	dBc

**Table 8. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH;  $f_1 = 619.5\text{ MHz}; f_2 = 649.5\text{ MHz}$ ; RF performance at  $V_{DS} = 48\text{ V}; I_{Dq} = 400\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.5\text{ V}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 617 MHz to 652 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$PAR_O$	output peak-to-average ratio	$P_{L(AV)} = 110\text{ W}$	5.6	6.3	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)} = 110\text{ W}$	391	465	-	W

## 7. Test information

### 7.1 Ruggedness in Doherty operation

The BLP9H10S-350A is capable of withstanding a load mismatch corresponding to  $V_{SWR} = 10 : 1$  through all phases under the following conditions:  $V_{DS} = 52 \text{ V}$ ;  $I_{Dq} = 400 \text{ mA}$ ;  $V_{GS(amp)peak} = 0.50 \text{ V}$ ;  $f = 634 \text{ MHz}$ ;  $P_L = 140 \text{ W}$  (5 dB OBO); pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10\%$ ).

### 7.2 Impedance information

**Table 9. Typical impedance of main device**

Measured load-pull data of main device;  $I_{Dq} = 400 \text{ mA}$  (main);  $V_{DS} = 48 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10\%$ ).

f (MHz)	Z <sub>S</sub> [1] (Ω)	Z <sub>L</sub> [1] (Ω)	P <sub>L</sub> [2] (W)	η <sub>D</sub> [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
600	7.9 – j3.22	2.6 + j0.4	217.8	62.6	17.8
617	7.5 – j2.85	2.6 + j0.4	231.3	67.6	18.3
635	6.9 – j2.50	2.6 + j0.4	224.2	66.8	18.6
652	6.4 – j2.81	2.5 + j0.4	197.3	61.5	17.9
698	5.5 – j3.05	2.0 + j0.3	225.8	64.4	18.7
720	5.2 – j3.45	2.0 + j0.3	229.0	66.2	19.0
746	5.0 – j4.15	2.6 – j0.3	224.2	62.0	18.4
769	4.9 – j4.72	2.6 – j0.3	224.9	63.2	18.5
805	4.9 – j5.54	2.6 – j0.3	220.0	62.8	18.4
820	4.9 – j5.93	2.1 + j0.0	223.9	65.1	18.5
869	5.6 – j7.48	2.1 + j0.0	217.7	66.4	18.5
880	5.7 – j7.87	2.1 + j0.0	214.6	66.1	18.6
894	6.2 – j8.35	2.8 – j0.9	211.9	58.3	17.6
915	6.7 – j8.98	2.1 + j0.0	214.9	67.9	18.5
925	7.1 – j9.30	2.0 – j0.7	217.1	59.5	17.3
942	7.8 – j9.84	2.0 – j0.8	218.6	60.9	17.2
960	8.7 – j10.40	2.0 – j0.7	217.1	61.4	17.2
<b>Maximum drain efficiency load</b>					
600	7.4 – j2.79	2.3 + j2.7	136.4	71.5	20.1
617	6.5 – j2.41	1.7 + j3.1	104.4	78.5	21.1
635	6.3 – j2.44	2.3 + j2.7	131.6	76.5	20.9
652	6.1 – j2.81	2.2 + j2.7	119.2	70.7	20.0
698	5.0 – j3.10	1.8 + j2.2	130.9	74.3	21.2
720	4.7 – j3.56	1.8 + j2.2	128.4	76.0	21.5
746	4.7 – j4.13	2.2 + j1.7	159.6	73.9	20.8
769	4.6 – j4.73	2.2 + j1.7	154.7	74.1	20.8
805	4.6 – j5.48	1.7 + j1.4	147.8	72.2	20.5
820	4.7 – j5.94	1.8 + j1.4	155.8	74.8	20.5

**Table 9. Typical impedance of main device ...continued**

Measured load-pull data of main device;  $I_{Dq} = 400$  mA (main);  $V_{DS} = 48$  V; pulsed CW ( $t_p = 100$   $\mu$ s;  $\delta = 10$  %).

f (MHz)	Z <sub>S</sub> [1] ( $\Omega$ )	Z <sub>L</sub> [1] ( $\Omega$ )	P <sub>L</sub> [2] (W)	$\eta_D$ [2] (%)	G <sub>p</sub> [2] (dB)
869	5.4 – j7.51	1.8 + j1.4	142.1	73.0	20.5
880	5.6 – j7.91	1.8 + j1.4	139.6	72.6	20.6
894	6.0 – j8.37	1.8 + j1.4	134.6	71.9	20.6
915	6.6 – j8.98	1.8 + j1.4	137.5	73.6	20.4
925	6.9 – j9.28	2.0 + j0.7	177.7	73.9	19.6
942	7.6 – j9.85	1.2 + j1.2	112.6	74.0	20.4
960	8.6 – j10.36	1.2 + j1.2	107.5	73.2	20.4

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.

**Table 10. Typical impedance of peak device**

Measured load-pull data of peak device;  $I_{Dq} = 600$  mA (peak);  $V_{DS} = 48$  V; pulsed CW ( $t_p = 100$   $\mu$ s;  $\delta = 10$  %).

f (MHz)	Z <sub>S</sub> [1] ( $\Omega$ )	Z <sub>L</sub> [1] ( $\Omega$ )	P <sub>L</sub> [2] (W)	$\eta_D$ [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
600	5.4 – j1.98	1.9 – j0.1	315.65	65.7	18.3
617	5.0 – j1.95	1.9 + j0.0	333.29	71.48	18.7
635	4.5 – j1.93	1.8 – j0.7	316.23	60.01	18.0
652	4.3 – j2.43	1.7 – j0.7	268.92	52.85	16.8
680	3.8 – j2.61	1.8 – j0.7	316.88	60.66	18.2
698	3.7 – j2.86	1.8 – j0.7	326.76	62.1	18.4
720	3.5 – j3.22	1.8 – j0.8	333.94	63.94	18.6
746	3.4 – j3.71	1.8 – j0.7	326.84	64.01	18.6
757	3.4 – j3.92	1.8 – j0.7	326.03	63.97	18.6
769	3.4 – j4.13	1.8 – j0.7	323.31	64.53	18.6
790	3.5 – j4.54	1.8 – j0.7	325.31	66.62	18.8
800	3.6 – j4.73	1.8 – j0.7	314.55	64.83	18.6
805	3.6 – j4.81	1.8 – j0.7	318.3	66.2	18.7
820	3.7 – j5.12	1.8 – j0.7	315.5	65.8	18.3
869	4.5 – j6.02	1.6 – j1.4	300.5	56.2	17.1
880	4.6 – j6.20	1.8 – j0.7	303.4	66.7	18.6
894	5.0 – j6.46	1.6 – j1.4	302.2	56.9	17.3
894	5.2 – j6.57	1.6 – j1.4	299.4	56.9	17.2
915	5.6 – j6.72	1.6 – j1.4	302.4	58.0	17.2
925	5.8 – j6.81	1.6 – j1.4	305.8	58.9	17.4
942	6.5 – j6.91	1.6 – j1.4	308.6	60.1	17.5
950	6.8 – j6.93	1.6 – j1.4	308.6	60.6	17.6
960	7.2 – j6.86	1.6 – j1.4	306.8	61.4	17.7

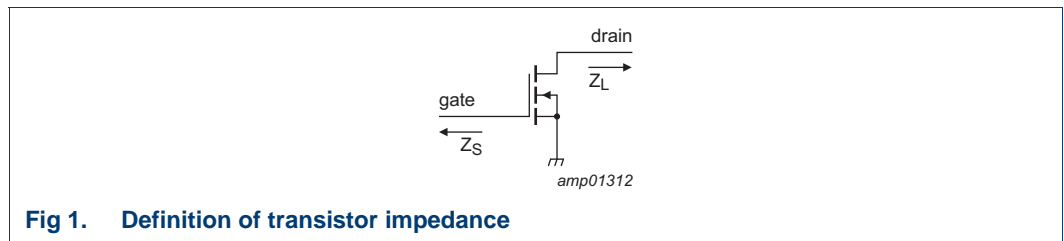
**Table 10. Typical impedance of peak device ...continued**

Measured load-pull data of peak device;  $I_{Dq} = 600 \text{ mA}$  (peak);  $V_{DS} = 48 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f (MHz)	$Z_S$ [1] ( $\Omega$ )	$Z_L$ [1] ( $\Omega$ )	$P_L$ [2] (W)	$\eta_D$ [2] (%)	$G_p$ [2] (dB)
<b>Maximum drain efficiency load</b>					
600	5.1 - j1.79	1.6 + j1.3	213.4	72.1	20.1
617	4.7 - j1.81	1.6 + j1.3	210.7	79.3	20.6
635	4.1 - j1.85	1.6 + j1.3	197.0	76.8	21.2
652	4.2 - j2.28	1.5 + j1.3	170.5	67.5	19.6
680	3.6 - j2.63	1.6 + j1.4	182.5	74.4	21.2
698	3.5 - j2.81	1.8 + j0.7	252.8	74.6	20.6
720	3.2 - j3.13	1.1 + j1.0	172.4	76.4	21.5
746	3.2 - j3.60	1.3 + j0.5	232.1	74.5	20.6
757	3.2 - j3.82	1.3 + j0.5	229.8	74.8	20.7
769	3.3 - j4.05	1.3 + j0.5	220.9	74.0	20.7
790	3.3 - j4.46	1.3 + j0.5	210.7	76.4	21.0
800	3.4 - j4.65	1.3 + j0.5	200.5	72.2	20.7
805	3.4 - j4.73	1.3 + j0.5	200.4	74.6	20.9
820	3.6 - j5.04	1.3 + j0.5	194.2	73.1	20.5
869	4.27 - j5.87	1.26 - j0.06	233.59	70.62	19.68
880	4.50 - j6.11	1.27 - j0.06	237.96	71.25	19.78
894	4.82 - j6.33	1.26 - j0.06	230.09	71.17	19.99
894	5.04 - j6.43	1.26 - j0.06	222.33	69.87	19.83
915	5.40 - j6.54	1.26 - j0.06	222.83	71.2	19.9
925	5.69 - j6.61	1.26 - j0.05	215.03	71.88	20.15
942	6.30 - j6.66	1.26 - j0.06	210.6	72.56	20.29
950	6.57 - j6.65	1.26 - j0.06	205.08	71.78	20.35
960	6.98 - j6.51	1.26 - j0.06	197.23	71.54	20.45

[1]  $Z_S$  and  $Z_L$  defined in [Figure 1](#).

[2] At 3 dB gain compression.



7.3 Test circuit

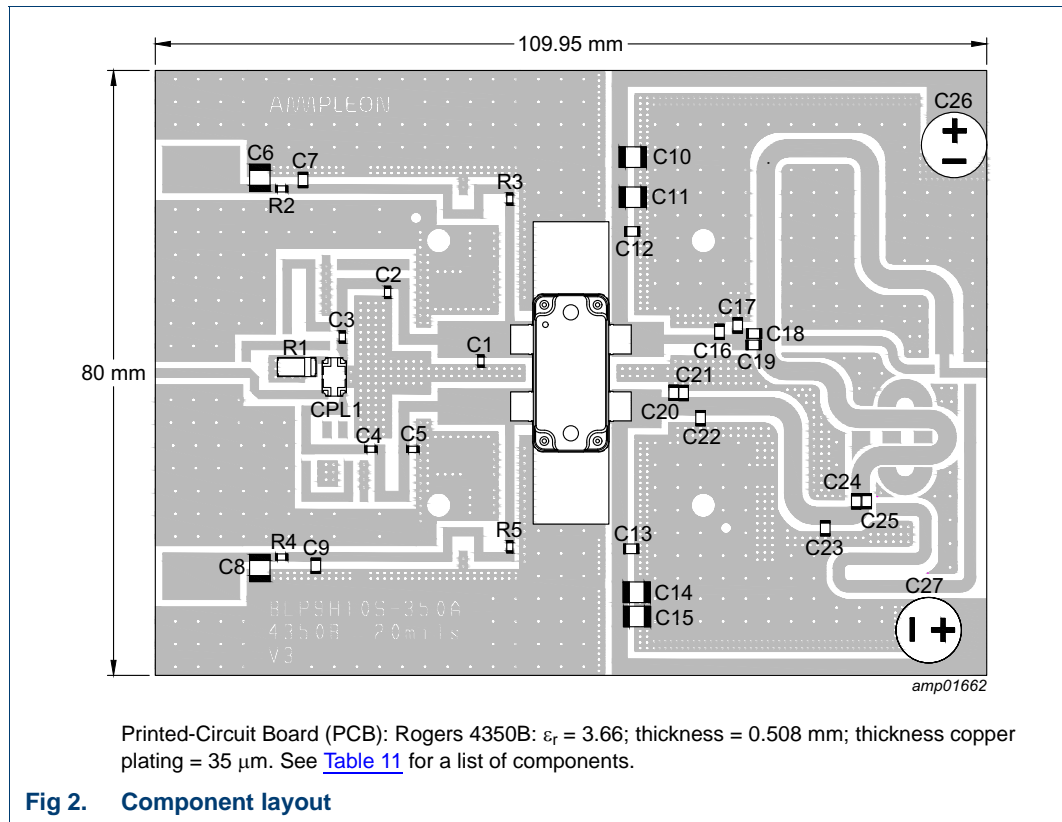


Fig 2. Component layout

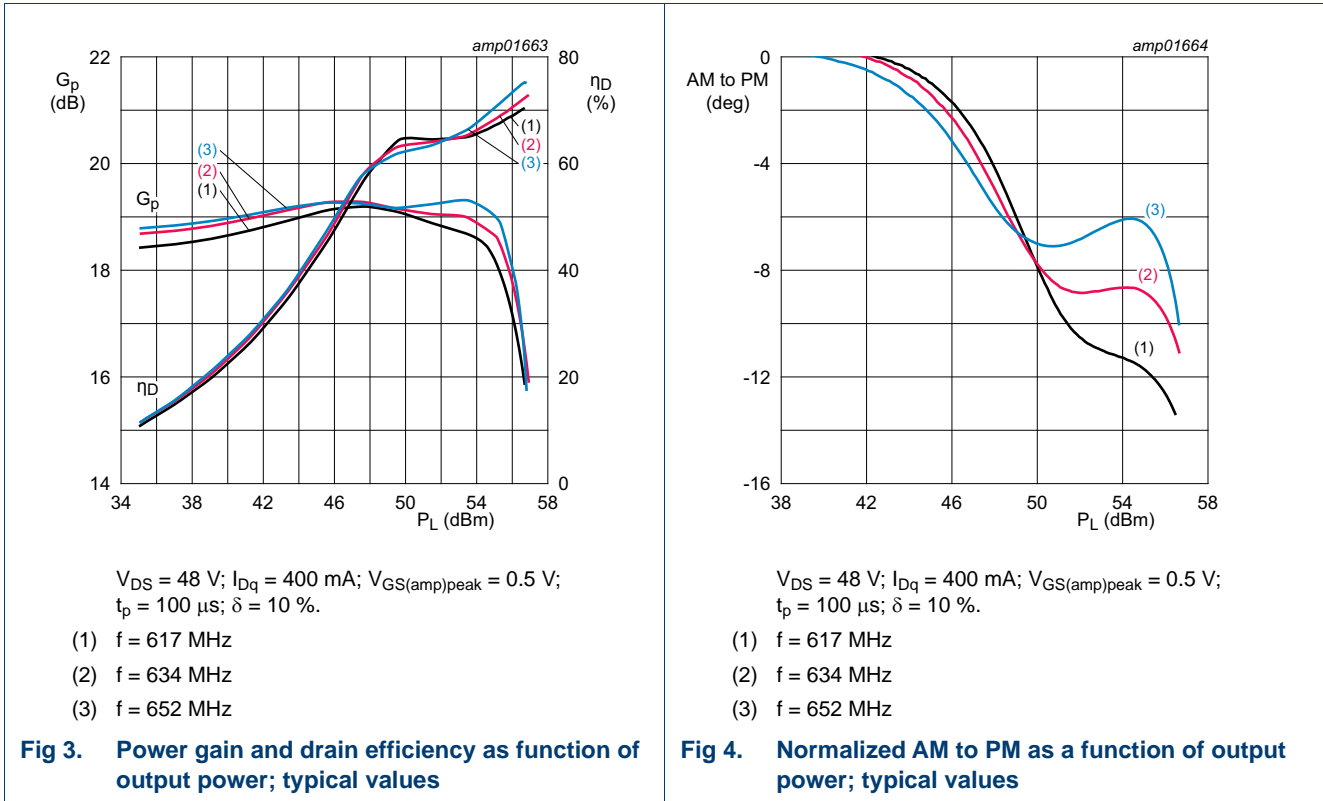
Table 11. List of components

See [Figure 2](#) for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	3.6 pF	Murata: GQM21 series
C2, C5, C24, C25	multilayer ceramic chip capacitor	10 pF	Murata: GQM21 series
C3	multilayer ceramic chip capacitor	20 pF	Murata: GQM21 series
C4	multilayer ceramic chip capacitor	47 pF	Murata: GQM21 series
C6, C8, C10, C11, C14, C15	multilayer ceramic chip capacitor	4.7 $\mu\text{F}$ , 100 V	Murata: GRM31CC72A475KE11L
C7, C9, C12, C13	multilayer ceramic chip capacitor	100 pF	Murata: GQM21 series
C16	multilayer ceramic chip capacitor	8.2 pF	Murata: GQM21 series
C17	multilayer ceramic chip capacitor	9.1 pF	Murata: GQM21 series
C18, C19	multilayer ceramic chip capacitor	22 pF	Murata: GQM21 series
C20, C21, C22	multilayer ceramic chip capacitor	12 pF	Murata: GQM21 series
C23	multilayer ceramic chip capacitor	2.0 pF	Murata: GQM21 series
C26, C27	electrolytic capacitor	470 $\mu\text{F}$ , 100 V	
R1	SMD resistor	50 $\Omega$ , 16 W	Anaren: C16A50Z4
R2, R3, R4, R5	SMD resistor	5.1 $\Omega$ , 1 %	0603
CPL1	hybrid coupler	2 dB, 90°	Anaren: X3C06F1-02S

7.4 Graphical data

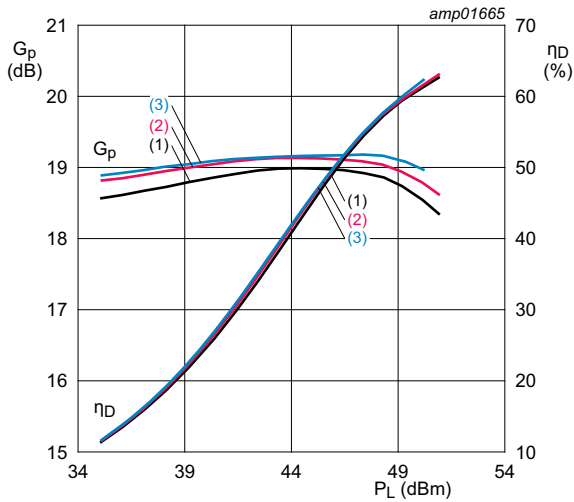
7.4.1 Pulsed CW





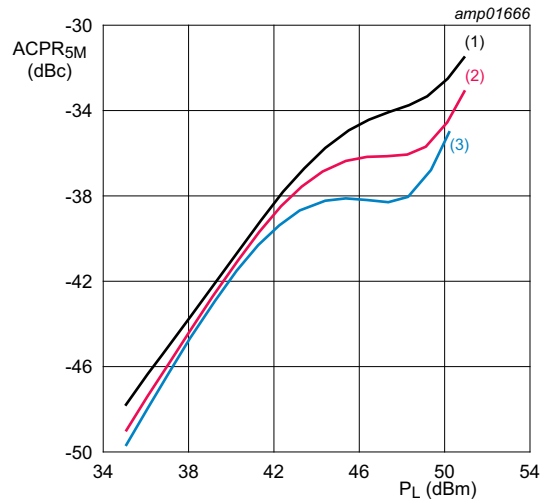
7.4.2 1-Carrier W-CDMA

PAR = 9.9 dB per carrier at 0.01 % probability on CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).



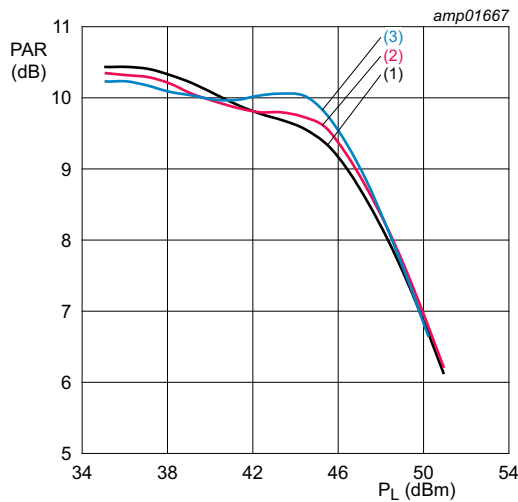
$V_{DS} = 48 \text{ V}; I_{Dq} = 400 \text{ mA}; V_{GS(amp)peak} = 0.5 \text{ V}.$   
 (1)  $f = 617 \text{ MHz}$   
 (2)  $f = 634 \text{ MHz}$   
 (3)  $f = 652 \text{ MHz}$

**Fig 5. Power gain and drain efficiency as function of output power; typical values**



$V_{DS} = 48 \text{ V}; I_{Dq} = 400 \text{ mA}; V_{GS(amp)peak} = 0.5 \text{ V}.$   
 (1)  $f = 617 \text{ MHz}$   
 (2)  $f = 634 \text{ MHz}$   
 (3)  $f = 652 \text{ MHz}$

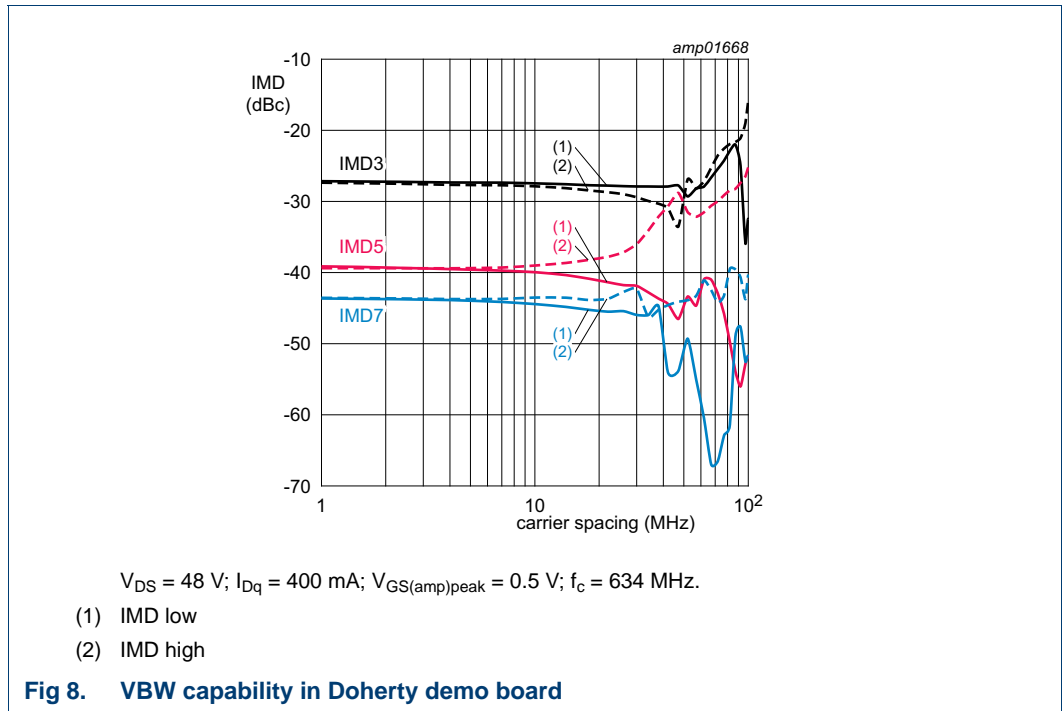
**Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values**



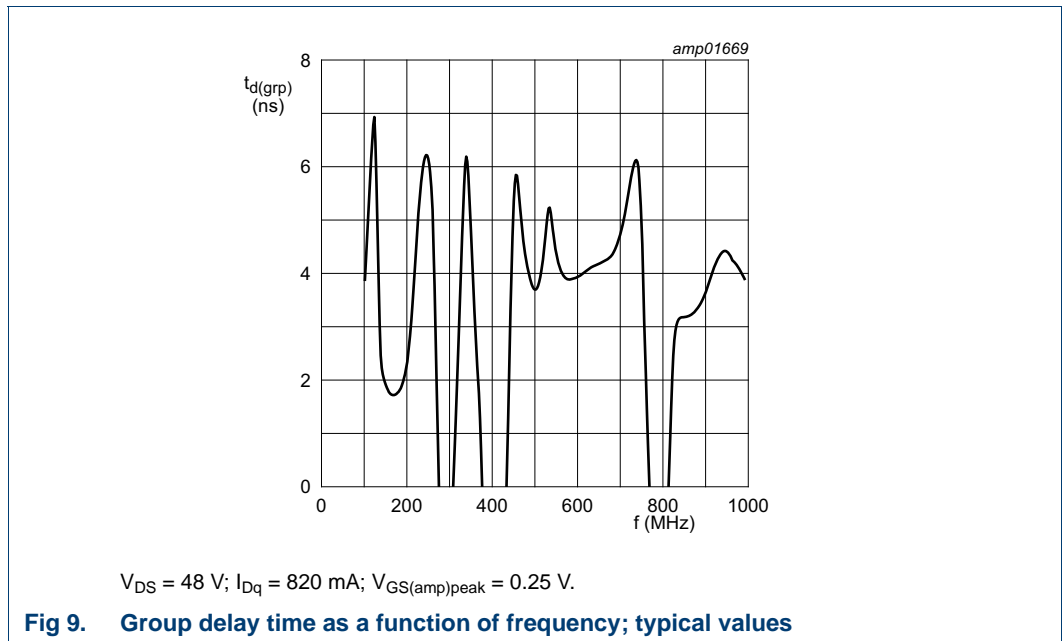
$V_{DS} = 48 \text{ V}; I_{Dq} = 400 \text{ mA}; V_{GS(amp)peak} = 0.5 \text{ V}.$   
 (1)  $f = 617 \text{ MHz}$   
 (2)  $f = 634 \text{ MHz}$   
 (3)  $f = 652 \text{ MHz}$

**Fig 7. Peak-to-average power ratio as a function of output power; typical values**

7.4.3 2-Tone VBW



7.4.4 Group delay



8. Package outline

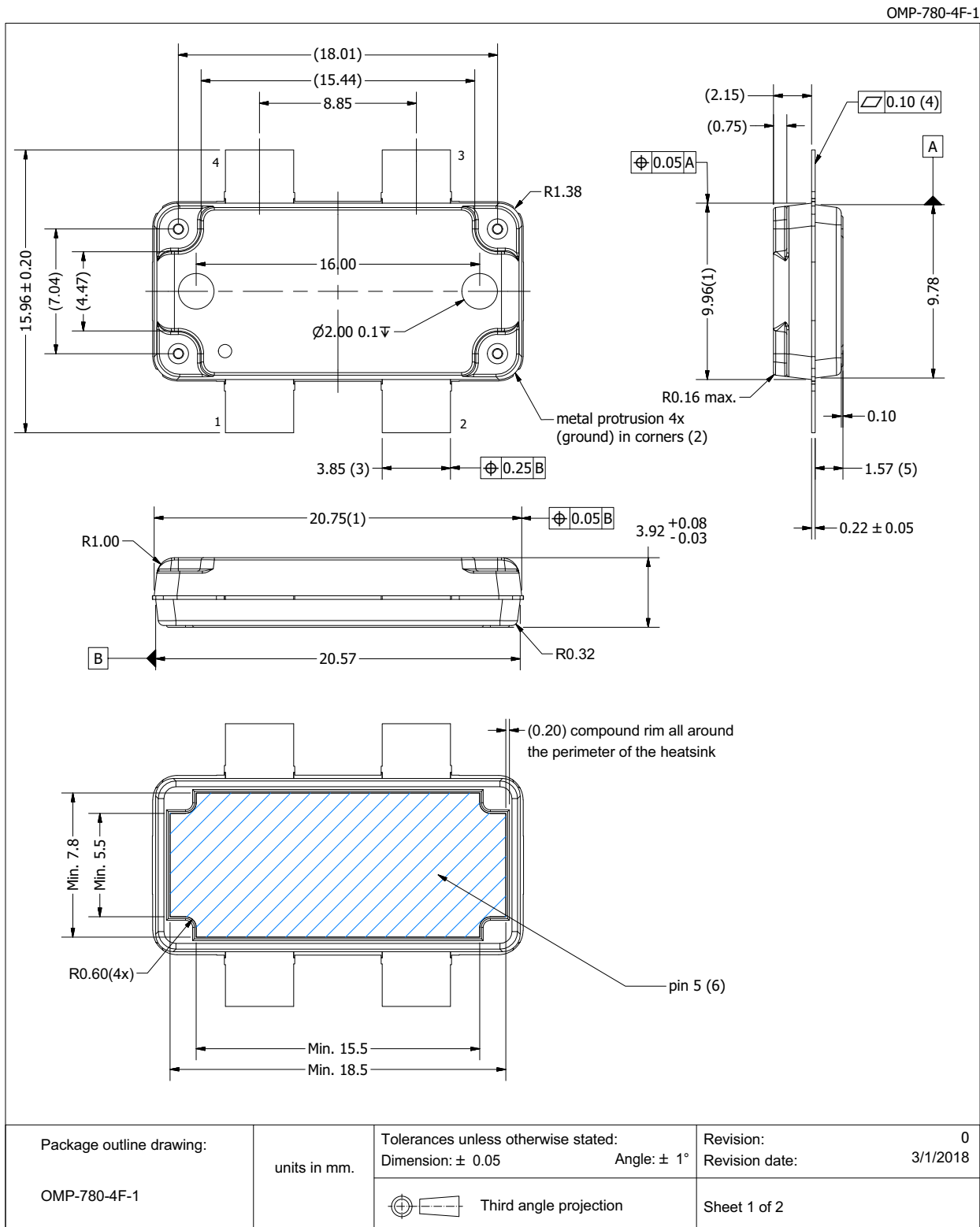
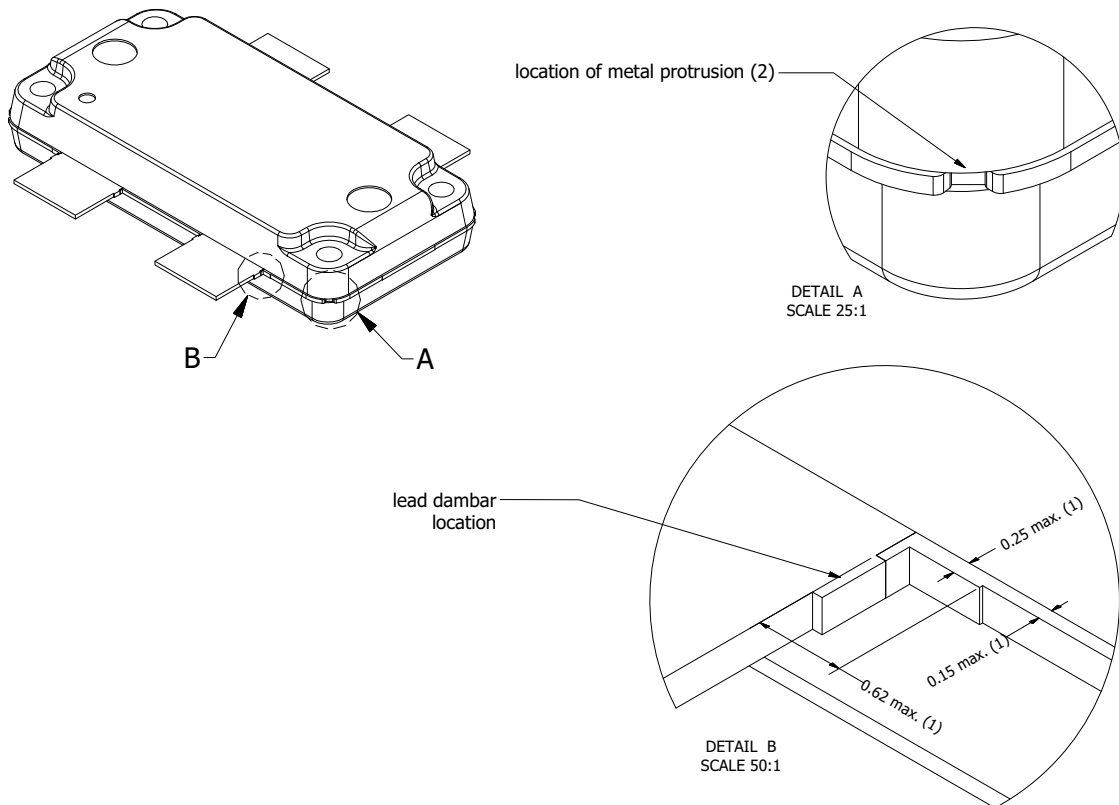


Fig 10. Package outline OMP-780-4F-1 (sheet 1 of 2)

OMP-780-4F-1

Drawing Notes	
Items	Description
(1)	Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.25 mm (per side) and max. 0.62 mm in length. At all other areas the mold protrusion is maximum 0.15 mm per side. See also detail B.
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.
(4)	The lead coplanarity over all leads is 0.1 mm maximum.
(5)	Dimension is measured 0.5 mm from the edge of the top package body.
(6)	The hatched area indicates the exposed metal heatsink.
(7)	The leads and exposed heatsink are plated with matte Tin (Sn).




Package outline drawing: OMP-780-4F-1	units in mm.	Tolerances unless otherwise stated: Dimension: $\pm 0.05$ Angle: $\pm 1^\circ$	Revision: 0 Revision date: 3/1/2018
		 Third angle projection	Sheet 2 of 2

Fig 11. Package outline OMP-780-4F-1 (sheet 2 of 2)

## 9. Handling information

**CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

**Table 12. ESD sensitivity**

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 <a href="#">[1]</a>
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 <a href="#">[2]</a>

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

## 10. Abbreviations

**Table 13. Abbreviations**

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VBW	Video Bandwidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

## 11. Revision history

**Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP9H10S-350A v.1	20210706	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

### 12.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

**Right to make changes** — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.ampleon.com/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

### 12.3 Disclaimers

**Maturity** — The information in this document can only be regarded as final once the relevant product(s) has passed the Release Gate in Ampleon's release process. Prior to such release this document should be regarded as a draft version.

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon's warranty of the product for such

automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon's standard warranty and Ampleon's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

## 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 13. Contact information

---

For more information, please visit: <http://www.ampleon.com>

For sales office addresses, please visit: <http://www.ampleon.com/sales>

14. Contents

1 **Product profile** ..... 1

1.1 General description ..... 1

1.2 Features and benefits ..... 1

1.3 Applications ..... 1

2 **Pinning information** ..... 2

3 **Ordering information** ..... 2

4 **Limiting values** ..... 2

5 **Thermal characteristics** ..... 2

6 **Characteristics** ..... 3

7 **Test information** ..... 4

7.1 Ruggedness in Doherty operation ..... 4

7.2 Impedance information ..... 4

7.3 Test circuit ..... 7

7.4 Graphical data ..... 8

7.4.1 Pulsed CW ..... 8

7.4.2 1-Carrier W-CDMA ..... 9

7.4.3 2-Tone VBW ..... 10

7.4.4 Group delay ..... 10

8 **Package outline** ..... 11

9 **Handling information** ..... 13

10 **Abbreviations** ..... 13

11 **Revision history** ..... 13

12 **Legal information** ..... 14

12.1 Data sheet status ..... 14

12.2 Definitions ..... 14

12.3 Disclaimers ..... 14

12.4 Trademarks ..... 15

13 **Contact information** ..... 15

14 **Contents** ..... 16

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Ampleon Netherlands B.V. 2021. All rights reserved.

For more information, please visit: <http://www.ampleon.com>  
 For sales office addresses, please visit: <http://www.ampleon.com/sales>

Date of release: 6 July 2021  
 Document identifier: BLP9H10S-350A